

Docket No.: 3885-0102P
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Hisashi YAMADA et al.

Application No.: 10/046,739

Confirmation No.: 2551

Filed: January 17, 2002

Art Unit: 2893

For: THIN-FILM CRYSTAL WAFER HAVING PN
JUNCTION AND METHOD FOR
FABRICATING THE WAFER

Examiner: N. V. Ngo

AMENDMENT IN RESPONSE TO NON-FINAL OFFICE ACTION

MS Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

INTRODUCTORY COMMENTS

In response to the Office Action dated October 28, 2009, please amend the above-identified U.S. patent application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 4 of this paper.